

# To Be Discontinued

- **Designed for European 868.95 MHz SRD Transmitters**
- **Very Low Series Resistance**
- **Quartz Stability**
- **Surface-mount Ceramic Case**

The RO3156A is a one-port surface-acoustic-wave (SAW) resonator packaged in a surface-mount ceramic case. It provides reliable, fundamental-mode quartz frequency stabilization of fixed-frequency transmitters operating at 868.95 MHz. The RO3156A is designed specifically for SRD transmitters operating in Europe under ETSI EN 300 220-2.

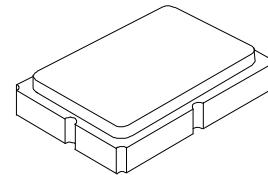
## Absolute Maximum Ratings

| Rating   | Value      | Units |
|--|------------|-------|
| CW RF Power Dissipation                              | +5         | dBm   |
| DC Voltage Between Terminals                         | $\pm 30$   | VDC   |
| Case Temperature                                     | -40 to +85 | °C    |
| Soldering Temperature, 10 seconds / 5 cycles maximum | 260        | °C    |

RoHS Compliance  
This component is compliant with RoHS directive.  
This component was always RoHS compliant from the first date of manufacture.

**RO3156A/A-1/A-2**

**868.95 MHz  
SAW Resonator**



**SM5035-4**

## Electrical Characteristics

| Characteristic                                     |                                      | Sym          | Notes      | Minimum  | Typical | Maximum   | Units               |
|--|--------------------------------------|--------------|------------|--|---------|-----------|---------------------|
| Frequency, +25 °C                                  | RO3156A                              | $f_C$        | 2,3,4,5    | 868.750  |         | 869.150   | MHz                 |
|  | RO3156A-1                            |              |            | 868.800  |         | 869.100   |                     |
|  | RO3156A-2                            |              |            | 868.850  |         | 869.050   |                     |
|  |                                      |              |            |  |         | $\pm 200$ |                     |
| Tolerance from 868.95 MHz                          | RO3156A                              | $\Delta f_C$ |            |  |         | $\pm 150$ | kHz                 |
|  | RO3156A-1                            |              |            |  |         | $\pm 100$ |                     |
|  | RO3156A-2                            |              |            |  |         |           |                     |
|  |                                      |              |            |  |         |           |                     |
| Insertion Loss                                     | IL                                   | 2,5,6        |            |  | 1.2     | 2.0       | dB                  |
| Quality Factor                                     | Unloaded Q                           | Q_U          | 5,6,7      |  | 6200    |           |                     |
|  | 50 Ω Loaded Q                        | Q_L          |            |  | 850     |           |                     |
| Temperature Stability                              | Turnover Temperature                 | T_O          | 6,7,8      | 10   | 25      | 40        | °C                  |
|  | Turnover Frequency                   | f_O          |            |  | $f_C$   |           | kHz                 |
|  | Frequency Temperature Coefficient    | FTC          |            |  | 0.032   |           | ppm/°C <sup>2</sup> |
| Frequency Aging                                    | Absolute Value during the First Year | fA           | 1          |  | <±10    |           | ppm/yr              |
| DC Insulation Resistance between Any Two Terminals |                                      |              | 5          | 1.0  |         |           | MΩ                  |
| RF Equivalent RLC Model                            | Motional Resistance                  | R_M          | 5, 6, 7, 9 |  | 14.5    |           | Ω                   |
|  | Motional Inductance                  | L_M          |            |  | 18.0    |           | μH                  |
|  | Motional Capacitance                 | C_M          |            |  | 2.0     |           | fF                  |
|  | Shunt Static Capacitance             | C_O          |            | 5, 6, 9  | 2.1     |           | pF                  |
| Test Fixture Shunt Inductance                      | L_TEST                               | 2, 7         |            |  | 15.8    |           | nH                  |
| Lid Symbolization                                  |                                      |              |            | RO3156A: 714, RO3156A-1: 923, RO3156A-2 828, //YYWWS |         |           |                     |

## CAUTION: Electrostatic Sensitive Device. Observe precautions for handling.

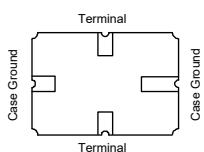
### NOTES:

- Frequency aging is the change in  $f_C$  with time and is specified at  $+65^\circ\text{C}$  or less. Aging may exceed the specification for prolonged temperatures above  $+65^\circ\text{C}$ . Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
- The center frequency,  $f_C$ , is measured at the minimum insertion loss point,  $\text{IL}_{\text{MIN}}$ , with the resonator in the  $50\ \Omega$  test system ( $\text{VSWR} \leq 1.2:1$ ). The shunt inductance,  $L_{\text{TEST}}$ , is tuned for parallel resonance with  $C_0$  at  $f_C$ . Typically,  $f_{\text{OSCILLATOR}} \text{ or } f_{\text{TRANSMITTER}}$  is approximately equal to the resonator  $f_C$ .
- One or more of the following United States patents apply: 4,454,488 and 4,616,197.
- Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
- Unless noted otherwise, case temperature  $T_C = +25 \pm 2^\circ\text{C}$ .

- The design, manufacturing process, and specifications of this device are subject to change without notice.
- Derived mathematically from one or more of the following directly measured parameters:  $f_C$ ,  $\text{IL}$ , 3 dB bandwidth,  $f_C$  versus  $T_C$ , and  $C_0$ .
- Turnover temperature,  $T_O$ , is the temperature of maximum (or turnover) frequency,  $f_O$ . The nominal frequency at any case temperature,  $T_C$ , may be calculated from:  $f = f_O [1 - \text{FTC} (T_O - T_C)^2]$ . Typically oscillator  $T_O$  is approximately equal to the specified resonator  $T_O$ .
- This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance  $C_0$  is the static (nonotional) capacitance between the two terminals measured at low frequency (10 MHz) with a capacitance meter. The measurement includes parasitic capacitance with "NC" pads unconnected. Case parasitic capacitance is approximately 0.05 pF. Transducer parallel capacitance can be calculated as:  $C_P \approx C_0 - 0.05 \text{ pF}$ .

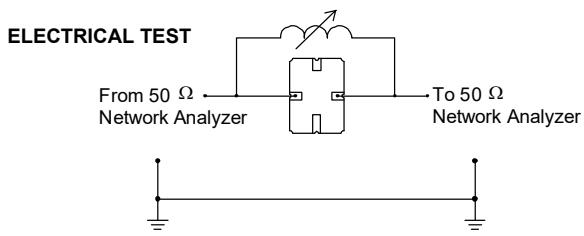
### Electrical Connections

The SAW resonator is bidirectional and may be installed with either orientation. The two terminals are interchangeable and unnumbered. The callout NC indicates no internal connection. The NC pads assist with mechanical positioning and stability. External grounding of the NC pads is recommended to help reduce parasitic capacitance in the circuit.



### Typical Test Circuit

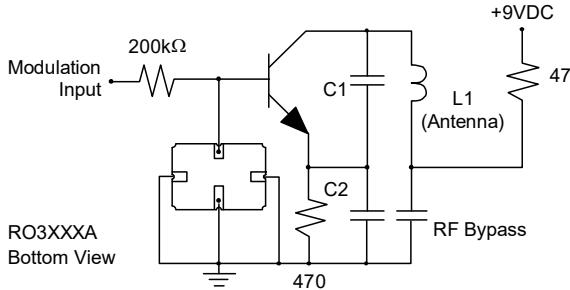
The test circuit inductor,  $L_{\text{TEST}}$ , is tuned to resonate with the static capacitance,  $C_0$ , at  $F_C$ .



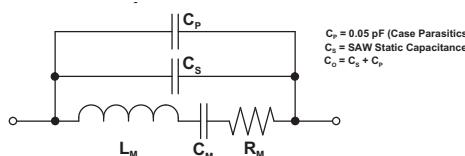
$$\text{CW RF Power Dissipation} = P_{\text{INCIDENT}} - P_{\text{REFLECTED}}$$

### Typical Application Circuits

#### Typical Low-Power Transmitter Application



### Equivalent RLC Model



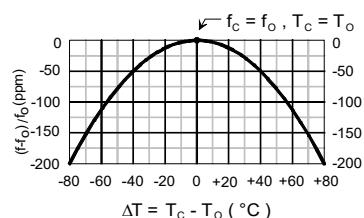
$$C_P = 0.05 \text{ pF (Case Parasitics)}$$

$$C_S = \text{SAW Static Capacitance}$$

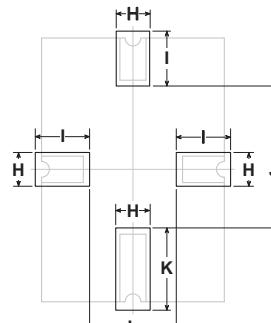
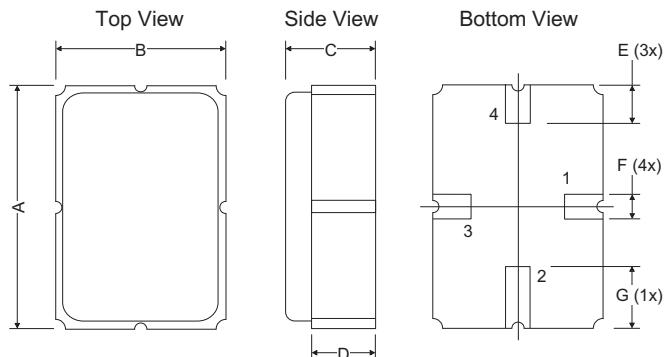
$$C_0 = C_S + C_P$$

### Temperature Characteristics

The curve shown on the right accounts for resonator contribution only and does not include LC component temperature contributions.

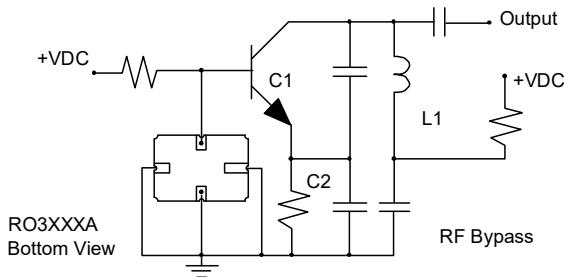


### Case



PCB Land Pattern  
Top View

### Typical Local Oscillator Applications



| Dimensions | Millimeters |      |      | Inches |       |       |
|------------|-------------|------|------|--------|-------|-------|
|            | Min         | Nom  | Max  | Min    | Nom   | Max   |
| A          | 4.87        | 5.00 | 5.13 | 0.191  | 0.196 | 0.201 |
| B          | 3.37        | 3.50 | 3.63 | 0.132  | 0.137 | 0.142 |
| C          | 1.45        | 1.53 | 1.60 | 0.057  | 0.060 | 0.062 |
| D          | 1.35        | 1.43 | 1.50 | 0.040  | 0.057 | 0.059 |
| E          | 0.67        | 0.80 | 0.93 | 0.026  | 0.031 | 0.036 |
| F          | 0.37        | 0.50 | 0.63 | 0.014  | 0.019 | 0.024 |
| G          | 1.07        | 1.20 | 1.33 | 0.042  | 0.047 | 0.052 |
| H          | -           | 1.04 | -    | -      | 0.041 | -     |
| I          | -           | 1.46 | -    | -      | 0.058 | -     |
| J          | -           | 3.01 | -    | -      | 0.119 | -     |
| K          | -           | 1.44 | -    | -      | 0.057 | -     |
| L          | -           | 1.92 | -    | -      | 0.076 | -     |

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